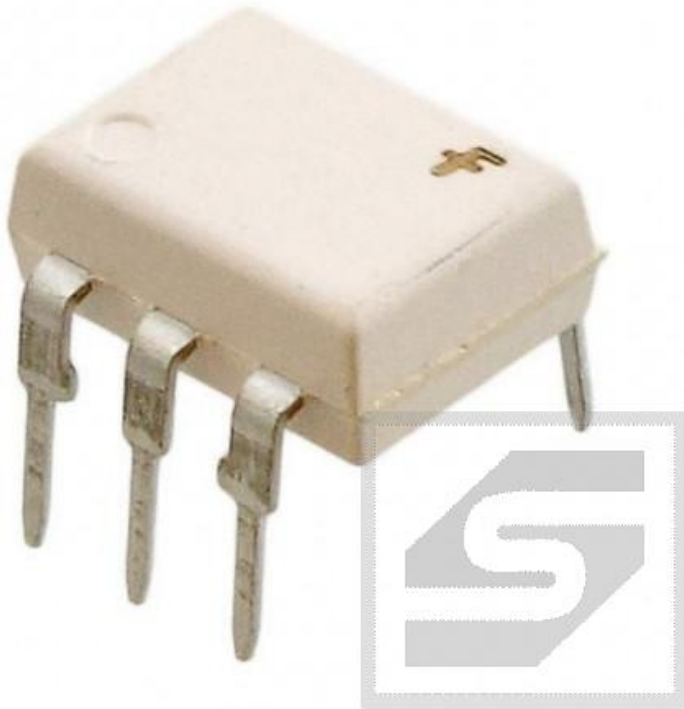




# Optotriak MOC3023 FAIRCHILD DIP6 RoHS



## **Dane techniczne:**

Nazwa: MOC3023

Typ elementu półprzewodnikowego: optotriak

Napięcie izolacji: 5kV

Napięcie wyjściowe: 400V

Rodzaj wyjścia: bez układu przełączania w zerze

Obudowa: DIP6

Napięcie wsteczne maksymalne: 6V

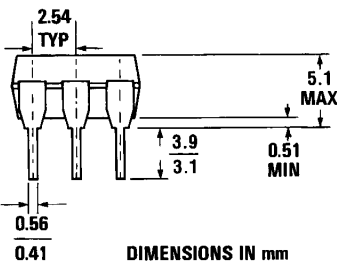
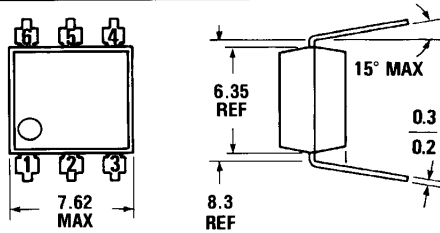
Prąd wyzwiania: 5mA

Montaż: THT

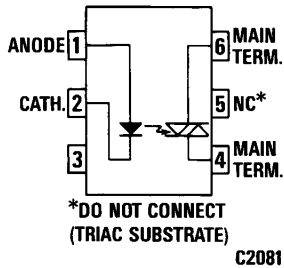
Liczba kanałów: 1

**MOC3020 MOC3021  
MOC3022 MOC3023**

**PACKAGE DIMENSIONS**



ST1603



Equivalent Circuit

**DESCRIPTION**

The MOC3020, MOC3021, MOC3022 and MOC3023 are optically isolated triac driver devices. These devices contain a GaAs infrared emitting diode and a light activated silicon bilateral switch, which functions like a triac. This is designed for interfacing between electronic controls and power triacs to control resistive and inductive loads for 240 VAC operations.

**FEATURES**

- Excellent  $I_{FT}$  stability—IR emitting diode has low degradation
- High isolation voltage—minimum 7500 VAC peak
- Underwriters Laboratory (UL) recognized—File #E90700

**APPLICATIONS**

- European applications for 240 VAC
- Triac driver
- Industrial controls
- Traffic lights
- Vending machines
- Motor control
- Solid state relay

**ABSOLUTE MAXIMUM RATINGS**

**TOTAL PACKAGE**

Storage temperature .....	-55°C to 150°C
Operating temperature .....	-40°C to 100°C
Lead temperature (soldering, 10 sec) .....	260°C

**INPUT DIODE**

Forward DC current .....	50 mA
Reverse voltage .....	3 V
Peak forward current (1 $\mu$ s pulse, 300 pps) .....	3.0 A
Power dissipation (25°C ambient) .....	100 mW
Derate linearly (above 25°C ambient) .....	1.33 mW/°C

**OUTPUT DRIVER**

Off-state output terminal voltage .....	400 Volts
On-state RMS current (Full cycle, 50 to 60 Hz) .....	$T_A=25^\circ\text{C}$ 100 mA $T_A=70^\circ\text{C}$ 50 mA
Peak nonrepetitive surge current (PW=10 ms, DC=10%) .....	1.2 A
Total power dissipation (25°C ambient) .....	300 mW
Derate above 25°C .....	4.0 mW/°C



## NON-ZERO-CROSSING TRIACS

### ELECTRO-OPTICAL CHARACTERISTICS (25°C Temperature Unless Otherwise Specified)

#### INDIVIDUAL COMPONENT CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
<b>INPUT DIODE</b>						
Forward voltage	$V_F$		1.2	1.50	V	$I_F = 10 \text{ mA}$
Junction capacitance	$C_J$		50		pF	$V_F = 0 \text{ V}$ , $f = 1 \text{ MHz}$
Reverse leakage current	$I_R$			100	$\mu\text{A}$	$V_R = 3.0 \text{ V}$
<b>OUTPUT DETECTOR</b>						
Peak blocking current, either direction	$I_{DRM}$	—	10	100	nA	$V_{DRM} = 400 \text{ V}$ , Note 1
Peak on-state voltage, either direction	$V_{TM}$	—	2.5	3.0	Volts	$I_{TM} = 100 \text{ mA Peak}$

Note 1. Test voltage must be applied within dv/dt rating.

#### TRANSFER CHARACTERISTICS

DC CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS	
LED trigger current (current required to latch output)	MOC3020	$I_{FT}$	—	—	30	mA	Main terminal voltage = 3.0 V, $R_L = 150\Omega$
	MOC3021	$I_{FT}$	—	—	15	mA	
	MOC3022	$I_{FT}$	—	—	10	mA	
	MOC3023	$I_{FT}$	—	—	5	mA	
Holding current	$I_H$	—	100	—	$\mu\text{A}$	Either direction	

#### TRANSFER CHARACTERISTICS

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
<b>dv/dt RATING</b>						
Critical rate of rise of off-state voltage	dv/dt	—	12	—	V/ $\mu\text{s}$	Static dv/dt, $T_A = 85^\circ\text{C}$ (see Fig. 3)
Critical rate of rise of commutating voltage	dv/dt	—	0.2	—	V/ $\mu\text{s}$	Commutating dv/dt $I_{LOAD} = 15 \text{ mA}$ (see Fig. 4)

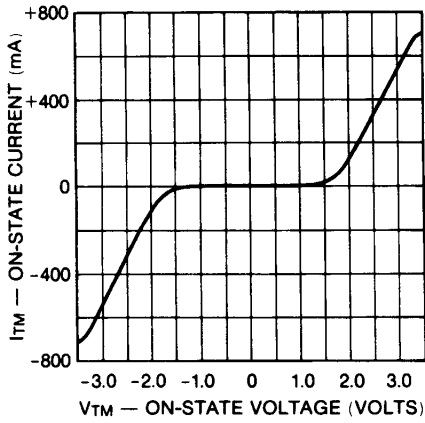
#### ISOLATION CHARACTERISTICS

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Isolation voltage	$V_{ISO}$	5300			$V_{ACRMS}$	$I_{IO} \leq 1 \mu\text{A}$ , 1 Minute
	$V_{ISO}$	7500			$V_{ACPEAK}$	$I_{IO} \leq 1 \mu\text{A}$ , 1 Minute
Isolation resistance	$R_{ISO}$	$10^{11}$			ohms	$V_{IO} = 500 \text{ VDC}$
Isolation capacitance	$C_{ISO}$		0.5		pF	$f = 1 \text{ MHz}$

Note 1: Ratings apply to either polarity of pin 6 — referenced to pin 4. Voltages must be applied within dv/dt rating.

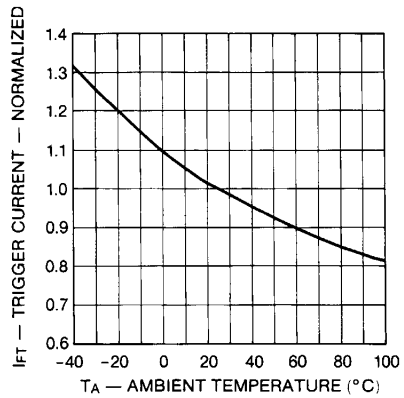
**TYPICAL ELECTRICAL CHARACTERISTIC CURVES**

(25°C Free Air Temperature Unless Otherwise Specified)



C1711

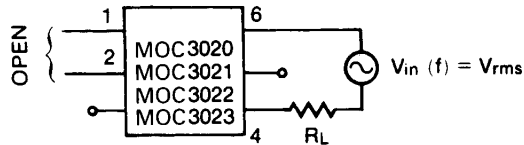
Fig. 1. On-State Characteristics



C1712

Fig. 2. Trigger Current vs. Temperature

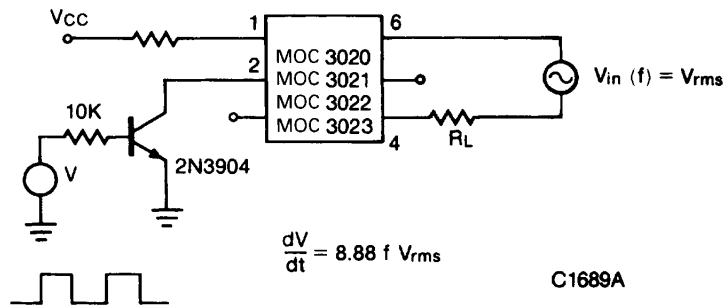
**TEST CIRCUITS FOR dV/dt MEASUREMENTS**



$$\frac{dV}{dt} = \omega V_{\text{pack}} = 2\pi f \times 1.414 V_{\text{rms}}$$

$$= 8.88 f V_{\text{rms}}$$

Fig. 3. Static dV/dt



$$\frac{dV}{dt} = 8.88 f V_{\text{rms}}$$

C1689A

Fig. 4. Commutating dV/dt

This datasheet has been download from:

[www.datasheetcatalog.com](http://www.datasheetcatalog.com)

Datasheets for electronics components.